NSN 5962-00-933-9961



Memory Microcircuit - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5962-00-933-9961 **Body Length:** 1.290 inches **Body Width:** Between 0.515 inches and 0.525 inches **Body Height:** 0.160 inches **Operating Tempurature Range:** -25.0/+70.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Monolithic and hermetically sealed and low power and bipolar and programmable and programmed and high speed and w/enable and positive outputs **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Dual-in-line **Output Logic Form:** P-type metal oxide-semiconductor logic **Input Circuit Pattern:** 11 input **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** -0.3 volts power source and 20.0 volts power source **Time Rating Per Chacteristic:** 1000.00 nanoseconds propagation delay time, low to high level output and 1000.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom **Test Data Document:** 80249-911265 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 24 printed circuit Shelf Life: N/a **Unit Of Measure: Demilitarization:**

Fiig: A458a0

No